# **Supporting Information**

### Highly efficient photoelectrochemical hydrogen generation using

## Zn<sub>x</sub>Bi<sub>2</sub>S<sub>3+x</sub> sensitized platelike WO<sub>3</sub> photoelectrodes

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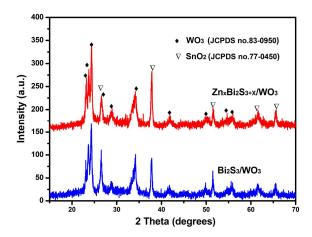
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### Supplementary methods

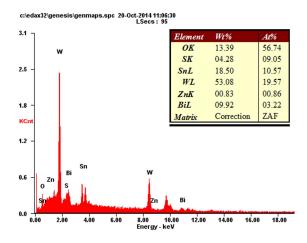
The crystalline phase of the electrodes was characterized by X-ray powder diffraction (XRD, D/Max2250, Rigaku Corporation, Japan). The local composition of  $Zn_xBi_2S_{3+x}/WO_3$  film was analyzed by an area scan of energy dispersive X-ray spectrometer (EDS) using scanning electron microscopy (SEM) and X-ray photoelectron spectroscopy (XPS). Raman spectra of the pure  $Bi_2S_3$  and  $Zn_xBi_2S_{3+x}$  films were recorded with a LabRAM HR800 Raman analyzer using an excitation laser source of 532 nm wavelength. The pure  $Bi_2S_3$  and  $Zn_xBi_2S_{3+x}$  films were prepared on

the FTO by a same SILAR method and the dipping procedure was repeated 30 times. Photocurrent-time plot of the photoelectrodes was obtained at -0.1 V vs. Ag/AgCl under continuous illumination. The Mott–Schottky plots of the photoelectrodes were measured by the electrochemical analyzer at the AC frequency of 1 kHz.

### Supplementary data



**Figure S1.** XRD patterns of Bi<sub>2</sub>S<sub>3</sub>/WO<sub>3</sub> film and Zn<sub>x</sub>Bi<sub>2</sub>S<sub>3+x</sub>/WO<sub>3</sub> film



**Figure S2.** EDS spectra of  $Zn_xBi_2S_{3+x}/WO_3$  film.

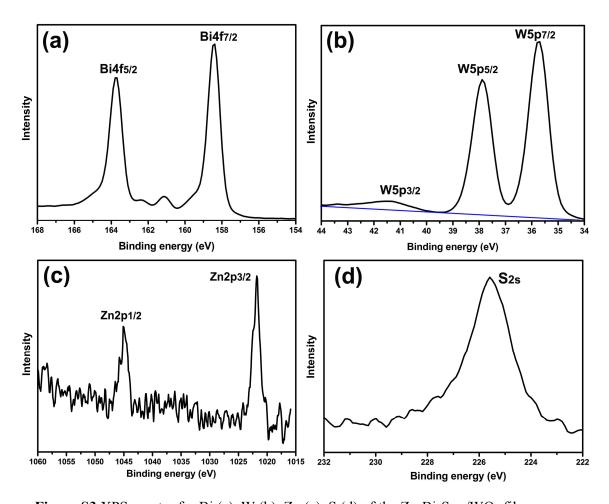


Figure S3 XPS spectra for Bi (a), W (b), Zn (c), S (d) of the  $Zn_xBi_2S_{3+x}/WO_3$  film

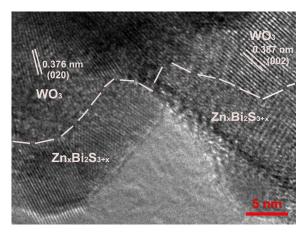


Figure S4. HRTEM images of  $Zn_xBi_2S_{3+x}/WO_3$  plate

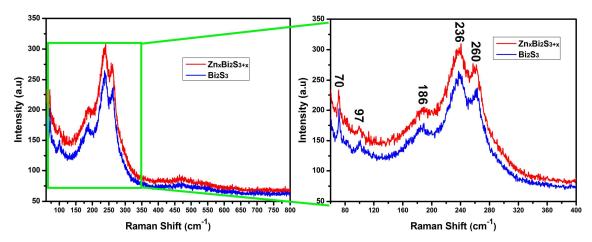


Figure S5. Raman spectrum of pure  $Bi_2S_3$  and  $Zn_xBi_2S_{3+x}$  film on the FTO substrates

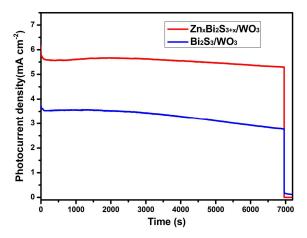


Figure S6. Photocurrent-time plot of the photoelectrodes at -0.1 V vs Ag/AgCl.

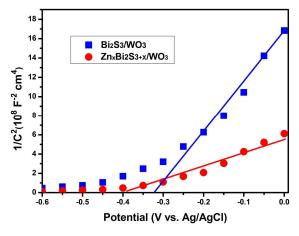


Figure S7. Mott–Schottky plots of the photoelectrodes